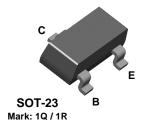


2N5088 2N5089

MMBT5088 MMBT5089





NPN General Purpose Amplifier

This device is designed for low noise, high gain, general purpose amplifier applications at collector currents from $1\mu A$ to 50 mA.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V_{CEO}	Collector-Emitter Voltage	2N5088	30	V
		2N5089	25	V
V_{CBO}	Collector-Base Voltage	2N5088	35	V
		2N5089	30	V
V _{EBO}	Emitter-Base Voltage		4.5	V
I _C	Collector Current - Continuous		100	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range		-55 to +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	M	Units	
		2N5088 2N5089	*MMBT5088 *MMBT5089	
P _D	Total Device Dissipation	625	350	mW
	Derate above 25°C	5.0	2.8	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	°C/W

^{*}Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

(continued)

			istics

TA = 25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min	Max	Units	
OFF CHAF	RACTERISTICS					
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	Ic = 1.0 mA, I _B = 0	5088 5089	30 25		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \ \mu\text{A}, \ I_E = 0$	5088 5089	35 30		V V
СВО	Collector Cutoff Current	V _{CB} = 20 V, I _E = 0 V _{CB} = 15 V, I _E = 0	5088 5089		50 50	nA nA
EBO	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_{C} = 0$			50	nA
		$V_{EB} = 4.5 \text{ V}, I_{C} = 0$			100	nA
	ACTERISTICS	V _{EB} = 4.5 V, I _C = 0			100	nA_
ON CHAR	ACTERISTICS DC Current Gain	$V_{EB} = 4.5 \text{ V}, I_C = 0$ $I_C = 100 \mu\text{A}, V_{CE} = 5.0 \text{ V}$ $I_C = 1.0 m\text{A}, V_{CE} = 5.0 \text{ V}$	5088 5089 5088	300 400 350 450	900 1200	nA
		$I_C = 100 \mu A, V_{CE} = 5.0 \text{ V}$	5089	400	900	nA
ON CHAR		$I_C = 100 \mu A, V_{CE} = 5.0 \text{ V}$ $I_C = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	5089 5088 5089 5088	400 350 450 300	900	nA V

SMALL SIGNAL CHARACTERISTICS

f⊤	Current Gain - Bandwidth Product	$I_C = 500 \mu A, V_{CE} = 5.0 \text{ mA},$ f = 20 MHz	50		MHz
C _{cb}	Collector-Base Capacitance	$V_{CB} = 5.0 \text{ V}, I_E = 0, f = 100 \text{ kHz}$		4.0	pF
C _{eb}	Emitter-Base Capacitance	$V_{BE} = 0.5 \text{ V}, I_{C} = 0, f = 100 \text{ kHz}$		10	pF
h _{fe}	Small-Signal Current Gain	I _C = 1.0 mA, V _{CE} = 5.0 V, 5088 f = 1.0 kHz 5089	350 450	1400 1800	
NF	Noise Figure	I_C = 100 μA, V_{CE} = 5.0 V, 5088 R_S = 10 kΩ, 5089 f = 10 Hz to 15.7 kHz		3.0 2.0	dB dB

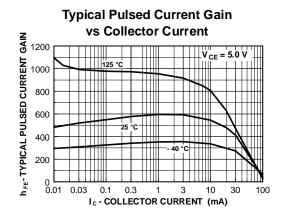
^{*}Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%

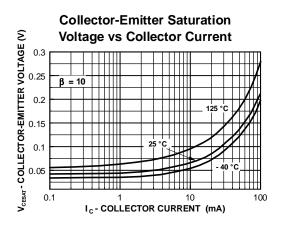
Spice Model

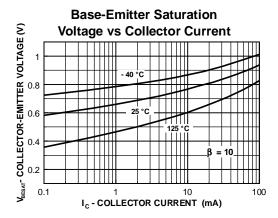
 $NPN \ (Is=5.911f \ Xti=3 \ Eg=1.11 \ Vaf=62.37 \ Bf=1.122K \ Ne=1.394 \ Is=5.911f \ Ikf=14.92m \ Xtb=1.5 \ Br=1.271 \ Nc=2 \ Isc=0 \ Ikr=0 \ Rc=1.61 \ Cjc=4.017p \ Mjc=.3174 \ Vjc=.75 \ Fc=.5 \ Cje=4.973p \ Mje=.4146 \ Vje=.75 \ Tr=4.673n \ Tf=821.7p \ Itf=.35 \ Vtf=4 \ Xtf=7 \ Rb=10)$

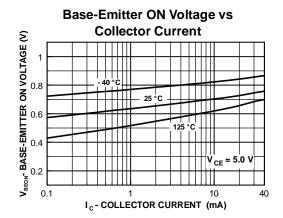
(continued)

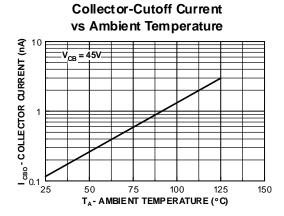
Typical Characteristics







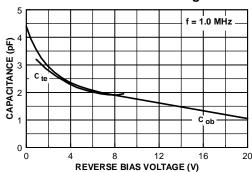




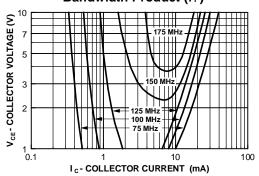
(continued)

Typical Characteristics (continued)

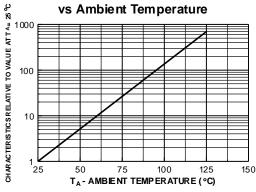
Input and Output Capacitance vs Reverse Bias Voltage



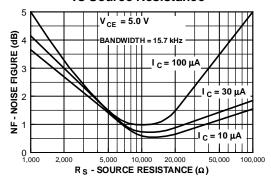
Contours of Constant Gain Bandwidth Product (f_T)



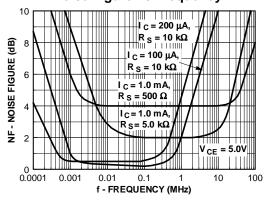
Normalized Collector-Cutoff Current vs Ambient Temperature



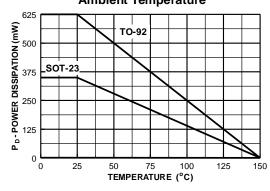
Wideband Noise Frequency vs Source Resistance



Noise Figure vs Frequency



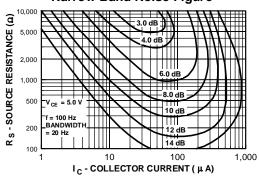
Power Dissipation vs Ambient Temperature



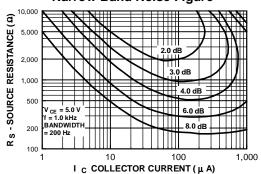
(continued)

Typical Characteristics (continued)

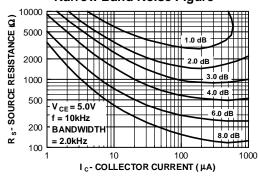
Contours of Constant Narrow Band Noise Figure



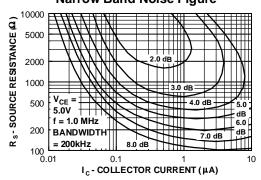
Contours of Constant Narrow Band Noise Figure



Contours of Constant Narrow Band Noise Figure



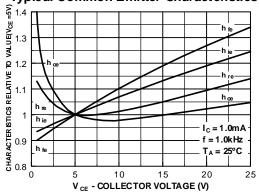
Contours of Constant Narrow Band Noise Figure



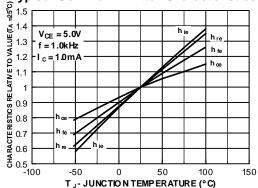
(continued)

Typical Common Emitter Characteristics (f = 1.0 kHz)

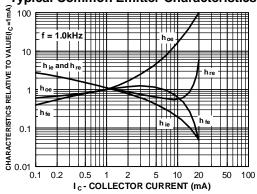




Typical Common Emitter Characteristics



Typical Common Emitter Characteristics



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2N5088

NPN General Purpose Amplifier

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General description

This device is designed for low noise, high gain, general purpose amplifier applications at collector currents from 1µA to 50 mA.

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Product	Product status	Pb-free Status	Pricing*	Package type	Leads	Packing method	Package Marking Convention**
2N5088BU	Full Production	Full Production	\$0.025	<u>TO-92</u>	3	BULK	<u>Line 1:</u> 2N <u>Line 2:</u> 5088 <u>Line 3:</u> -&3
2N5088TA	Full Production	Full Production	\$0.025	<u>TO-92</u>	3	AMMO	<u>Line 1:</u> 2N <u>Line 2:</u> 5088 <u>Line 3:</u> -&3
2N5088TAR	Full Production	Full Production	\$0.025	<u>TO-92</u>	3	AMMO	Line 1: 2N Line 2: 5088 Line 3: -&3
2N5088TA_NL	Full Production		N/A	<u>TO-92</u>	3	АММО	Line 1: 2N Line 2: 5088 Line 3: -&3

		Full Production					
2N5088TF	Full Production	Full Production	\$0.025	<u>TO-92</u>	3	TAPE REEL	<u>Line 1:</u> 2N <u>Line 2:</u> 5088 <u>Line 3:</u> -&3
2N5088TFR	Full Production	Full Production	\$0.025	<u>TO-92</u>	3	TAPE REEL	<u>Line 1:</u> 2N <u>Line 2:</u> 5088 <u>Line 3:</u> -&3
2N5088_D81Z	Full Production	Full Production	N/A	<u>TO-92</u>	3	TAPE REEL	Line 1: \$Y (Fairchild logo) & Z (Asm. Plant Code) & 3 (3-Digit Date Code) Line 2: 2N Line 3: 5088
2N5088_J61Z	Full Production	Full Production	N/A	<u>TO-92</u>	3	BULK	Line 1: \$Y (Fairchild logo) & Z (Asm. Plant Code) & 3 (3-Digit Date Code) Line 2: 2N Line 3: 5088

^{*} Fairchild 1,000 piece Budgetary Pricing

** A sample button will appear if the part is available through Fairchild's on-line samples program. If there is no sample button, please contact a Fairchild distributor to obtain samples



Indicates product with Pb-free second-level interconnect. For more information click here.

Package marking information for product 2N5088 is available. Click here for more information .

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Models

Package & leads	ads Condition Temperature range		Vcc range	Software version	Revision date
		PSPICE			
TO-92-3	Electrical/Thermal	-55°C to 150°C	0V to 35V	9.2	Jan 26, 2003

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Qualification Support

Click on a product for detailed qualification data

Product
<u>2N5088BU</u>
2N5088TA
2N5088TAR
2N5088TA_NL
2N5088TF
2N5088TFR
2N5088_D81Z
2N5088_J61Z

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